

30A, 120V Low V_F Schottky Barrier Rectifier

FEATURES

- AEC-Q101 qualified available
- Low power loss, high efficiency
- Guard ring for overvoltage protection
- High surge current capability
- UL Recognized File # E-326243
- RoHS Compliant
- Halogen-free according to IEC 61249-2-21

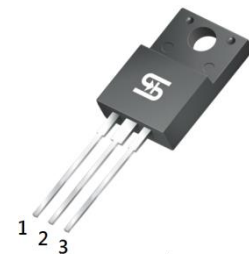
APPLICATIONS

- Switching mode power supply (SMPS)
- Adapters
- DC to DC converters

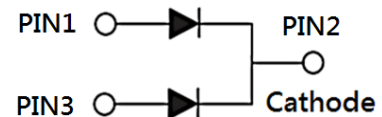
MECHANICAL DATA

- Case: ITO-220AB
- Molding compound meets UL 94V-0 flammability rating
- Terminal: Matte tin plated leads, solderable per J-STD-002
- Mounting torque: 0.56 N·m maximum
- Meet JESD 201 class 2 whisker test
- Polarity: As marked
- Weight: 1.70g (approximately)

KEY PARAMETERS		
PARAMETER	VALUE	UNIT
I_F	30	A
V_{RRM}	120	V
I_{FSM}	200	A
T_{JMAX}	150	°C
Package	ITO-220AB	
Configuration	Dual dies	



ITO-220AB



ABSOLUTE MAXIMUM RATINGS ($T_A = 25^\circ\text{C}$ unless otherwise noted)			
PARAMETER	SYMBOL	MBRF30L120CT	UNIT
Marking code on the device		MBRF30L120CT	
Repetitive peak reverse voltage	V_{RRM}	120	V
Reverse voltage, total rms value	$V_{R(RMS)}$	84	V
Forward current	I_F	30	A
Surge peak forward current, 8.3ms single half sine wave superimposed on rated load	I_{FSM}	200	A
Peak repetitive reverse surge current ⁽¹⁾	I_{RRM}	1	A
Peak repetitive forward current (Rated V_R , Square wave, 20KHz)	I_{FRM}	30	A
Critical rate of rise of off-state voltage	dv/dt	10,000	V/ μs
Junction temperature	T_J	-55 to +150	°C
Storage temperature	T_{STG}	-55 to +150	°C

Notes:

1. $t_p = 2.0\mu\text{s}$, 1.0KHz

THERMAL PERFORMANCE			
PARAMETER	SYMBOL	TYP	UNIT
Junction-to-case thermal resistance	$R_{\theta JC}$	5	°C/W

ELECTRICAL SPECIFICATIONS ($T_A = 25^\circ\text{C}$ unless otherwise noted)					
PARAMETER	CONDITIONS	SYMBOL	TYP	MAX	UNIT
Forward voltage per diode ⁽¹⁾	$I_F = 15\text{A}, T_J = 25^\circ\text{C}$	V_F	0.81	0.88	V
	$I_F = 30\text{A}, T_J = 25^\circ\text{C}$		0.89	0.95	V
	$I_F = 15\text{A}, T_J = 125^\circ\text{C}$		0.66	0.75	V
	$I_F = 30\text{A}, T_J = 125^\circ\text{C}$		0.76	0.82	V
Reverse current @ rated V_R per diode ⁽²⁾	$T_J = 25^\circ\text{C}$	I_R	-	20	μA
	$T_J = 125^\circ\text{C}$		-	25	mA

Notes:

1. Pulse test with $PW = 0.3\text{ms}$
2. Pulse test with $PW = 30\text{ms}$

ORDERING INFORMATION		
ORDERING CODE⁽¹⁾	PACKAGE	PACKING
MBRF30L120CT	ITO-220AB	50 / Tube
MBRF30L120CTH	ITO-220AB	50 / Tube

Notes:

1. "H" means AEC-Q101 qualified

CHARACTERISTICS CURVES

($T_A = 25^\circ\text{C}$ unless otherwise noted)

Fig.1 Forward Current Derating Curve

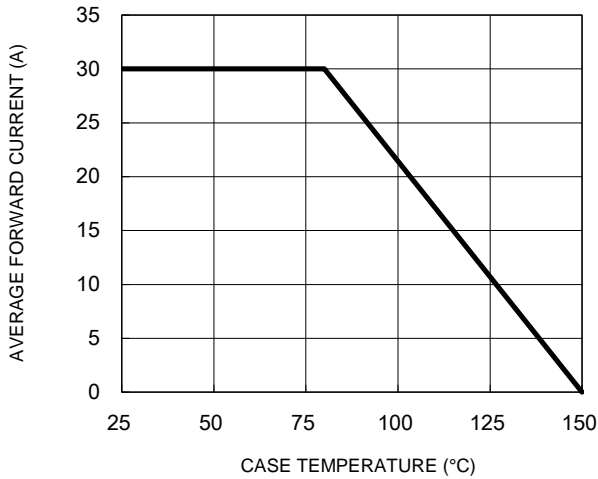


Fig.2 Typical Junction Capacitance

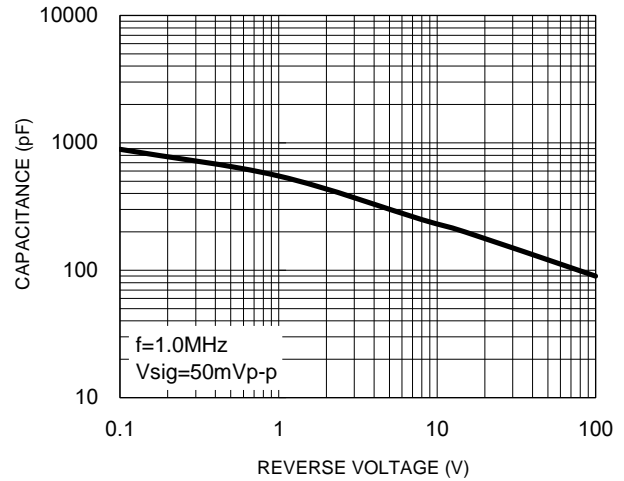


Fig.3 Typical Reverse Characteristics

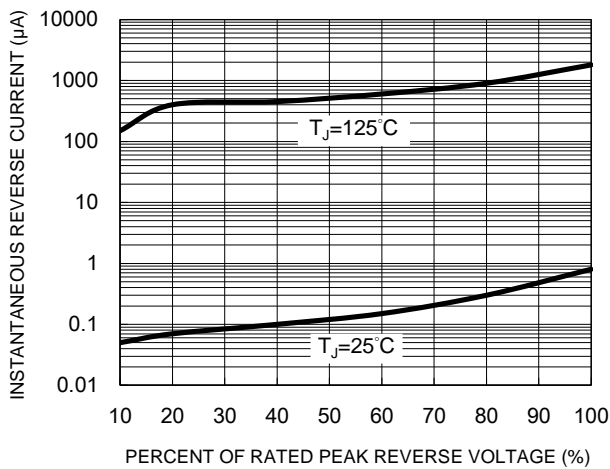


Fig.4 Typical Forward Characteristics

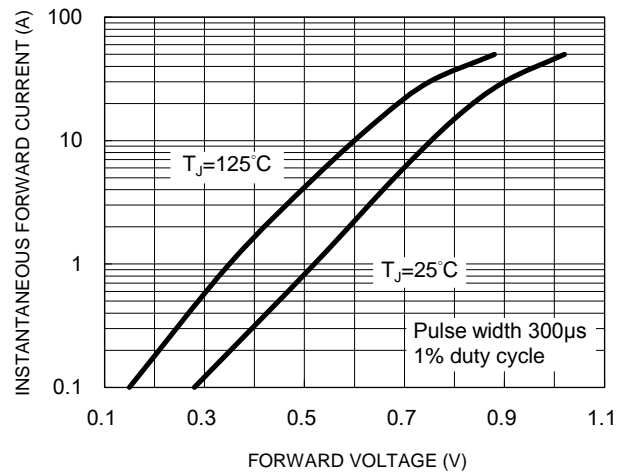
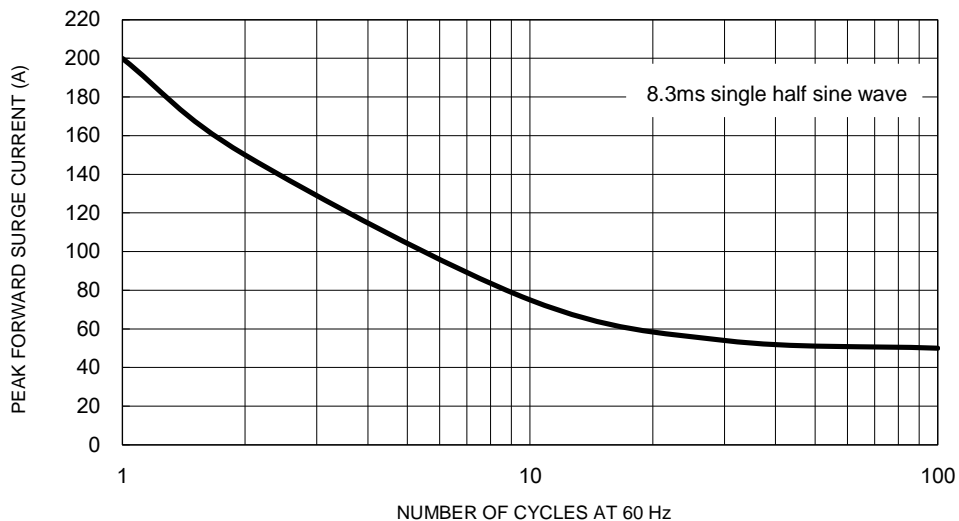


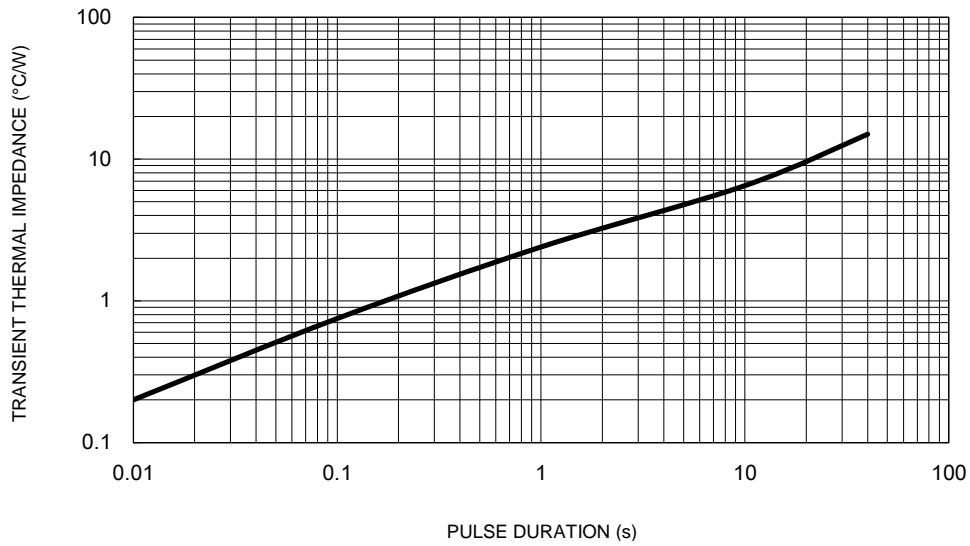
Fig.5 Maximum Non-Repetitive Forward Surge Current



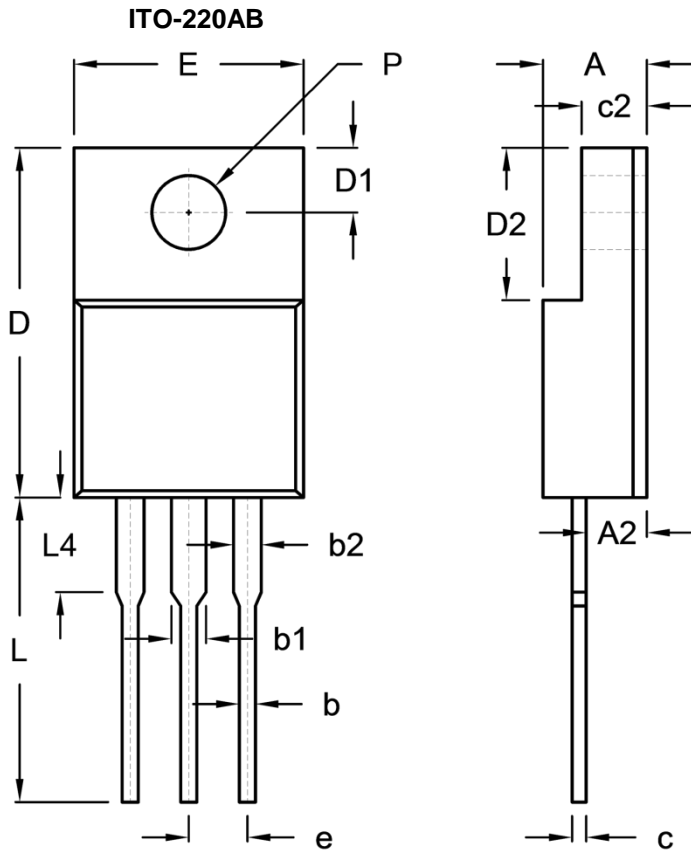
CHARACTERISTICS CURVES

($T_A = 25^\circ\text{C}$ unless otherwise noted)

Fig.6 Typical Transient Thermal Impedance



PACKAGE OUTLINE DIMENSIONS



DIM.	Unit (mm)		Unit (inch)	
	Min.	Max.	Min.	Max.
A	4.30	4.70	0.169	0.185
A2	2.30	2.96	0.091	0.117
b	0.50	0.90	0.020	0.035
b1	-	1.80	-	0.071
b2	0.95	1.45	0.037	0.057
c	0.46	0.76	0.018	0.030
c2	2.50	3.16	0.098	0.124
D	14.80	15.50	0.583	0.610
D1	2.40	3.20	0.094	0.126
D2	6.30	6.90	0.248	0.272
E	9.60	10.30	0.378	0.406
e	2.41	2.67	0.095	0.105
L	12.60	13.80	0.496	0.543
L4	-	4.10	-	0.161
P	3.00	3.40	0.118	0.134

MARKING DIAGRAM



- P/N = Marking Code
- G = Green Compound
- YWW = Date Code
- F = Factory Code